# NSN 5961-00-416-4897

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## **Inclosure Material:**

Metal

## **Overall Length:**

Between 0.250 inches and 0.340 inches

# **Overall Diameter:**

0.620 inches

# **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

-60.0 collector to base voltage/static/emitter open and -60.0 collector to emitter voltage/static/base open and -7.0 emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and -4.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

25.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

## **Special Features:**

Junction pattern arrangement: pnp

## Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

## **Specification Data:**

81349-mil-s-19500/441 government specification

## Shelf Life:

N/a

## Unit Of Measure:

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### Demilitarization:

No

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